

國立臺北科技大學九十八學年度碩士班招生考試

系所組別：2230 電腦與通訊研究所丙組

第二節 電子學 試題

第一頁 共一頁

**注意事項：**

1. 本試題共五題，配分共 100 分。
2. 請標明大題、子題編號作答，不必抄題。
3. 全部答案均須在答案卷之答案欄內作答，否則不予計分。

(請依序於答案卷之答案欄內作答)

一、 Please employ one 1:1 transformer, two PN junction diodes, and two capacitors to design a voltage-doubling circuit which delivers a dc voltage,  $V_{out}$ , equal to twice the transformer peak voltage,  $V_p$ , assuming that the forward cut-in voltages of the two diodes are both zero. (20%)

二、 Please show in detail that the transconductance of a depletion MOSFET operating in the saturation region is given by  $g_m = \left( \frac{2}{|V_p|} \right) \sqrt{I_{DSS} I_{DS}}$  where  $I_{DS}$  is the drain-to-source current,  $I_{DSS}$  is the value of the  $I_{DS}$  current for  $V_{GS} = 0$ , and  $V_p$  is the pinch-off voltage for the depletion MOSFET. (20%)

三、 Figure 1 is a Sallen-Key filter. Please show in detail that the transfer function of filter network is given by  $H(s) = \frac{V_{out}(s)}{V_{in}(s)} = \frac{\omega_0^2}{s^2 + 2\omega_0 s + \omega_0^2}$  where  $\omega_0 = \frac{1}{RC}$ . (20%)

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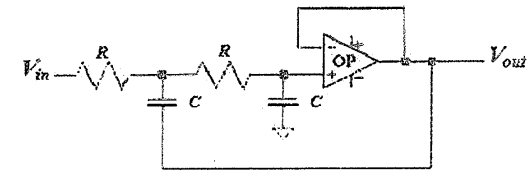


Figure 1

四、 Many oscillator circuits fall into the general form shown in Figure 2. Assuming that the amplifying device with an open-circuit voltage gain of  $-A_v$  exhibits infinitely high input resistance,  $R_m = \infty$ , but has a nonzero output resistance,  $R_{out} \neq 0$ , and  $Z_1 = jX_1, Z_2 = jX_2, Z_3 = jX_3$ , please prove in detail that the circuit in Figure 2 will oscillate at the resonant frequency that satisfies this oscillation condition  $(X_1 + X_2 + X_3) = 0$ . (20%)

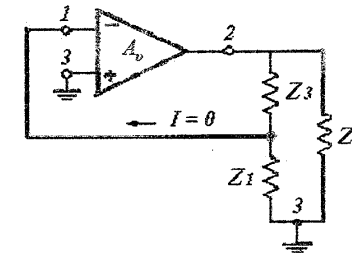


Figure 2

五、 The truth table of the J-K FLIP-FLOP is specified in Table 1. Please design the J-K FLIP-FLOP with four NAND logic gates. (20%)

Table 1

Clock	$J_n$	$K_n$	$Q_{n+1}$	$\overline{Q_{n+1}}$
1	0	0	$Q_n$	$\overline{Q_n}$
1	0	1	0	1
1	1	0	1	0
1	1	1	$\overline{Q_n}$	$Q_n$